AT Series - 0603





GENERAL DESCRIPTION

KYOCERA AVX's new PMC SMT Attenuator Series (AT) is manufactured with the highest quality materials for reliable and repeatable performance. These devices are constructed with Aluminum Nitride (AIN) and are available in a standard EIA 0603 case size. The AT Series exhibits excellent performance characteristics for the most demanding PMC applications

The AT series provides virtually flat loss over a broad frequency spectrum. Thin film metalization provides for very stable characteristics over temperature and time. Its balanced PI design provides even current distribution and accurate attenuation characteristics from DC to 20 GHz. It is designed to meet a wide range of RF and microwave large and small signal level applications. The AT is ideal for impedance matching, input padding, signal level runing, and many other critical PMC applications. The AT is rated highest power in class and is suitable for microstrip and CPW applications.

The non-magnetic termination is available providing a range of attachment options such as eutectic diebonding, conductive epoxies, and soldering. The AT is fully compatible with high speed automated pick-and-place processing.

Note: Consult Factory for other attenuation values, termination style and case sizes.

HOW TO ORDER

FEATURES

Thin Film Design

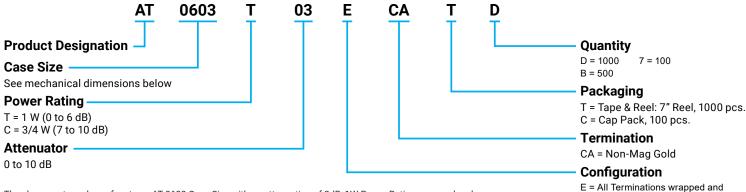
Power Rating Up to 1 Watt

Characterized to 20 GHz

CPW and Microstrip

Applications EIA 0603 SMT

Frequency Response +/-0.5dB



The above part number refers to an AT 0603 Case Size with an attenuation of 3dB, 1W Power Rating, wrapped and patterned ground plane configuration with Non-Mag Gold Termination and tape and reel packaging, 1000 pcs.

Highest Power in Class

AIN construction

Non-Magnetic

RoHs compliant

Balanced Pi design

APPLICATIONS

- Telecommunications
- Satellite Communications
- Cellular Base Stations
- Microwave Radio
- ISM
- RF/Microwave Power
- Military/Aerospace
- · Test and Measurement

patterned ground plane

- Impedance Matching
- Input Padding
- Signal Level Tuning
- Signal Conditioning

AVAILABLE ATTENUATOR VALUES

Part Number	dB	Impedance	Frequency Range	Power	Case Size
AT0603T00ECATD	0	50	DC - 20 Ghz	1	0603
AT0603T01ECATD	1	50	DC - 20 Ghz	1	0603
AT0603T02ECATD	2	50	DC - 20 Ghz	1	0603
AT0603T03ECATD	3	50	DC - 20 Ghz	1	0603
AT0603T04ECATD	4	50	DC - 20 Ghz	1	0603
AT0603T05ECATD	5	50	DC - 20 Ghz	1	0603
AT0603T06ECATD	6	50	DC - 20 Ghz	1	0603
AT0603C07ECATD	7	50	DC - 20 Ghz	0.75	0603
AT0603C08ECATD	8	50	DC - 20 Ghz	0.75	0603
AT0603C09ECATD	9	50	DC - 20 Ghz	0.75	0603
AT0603C10ECATD	10	50	DC - 20 Ghz	0.75	0603

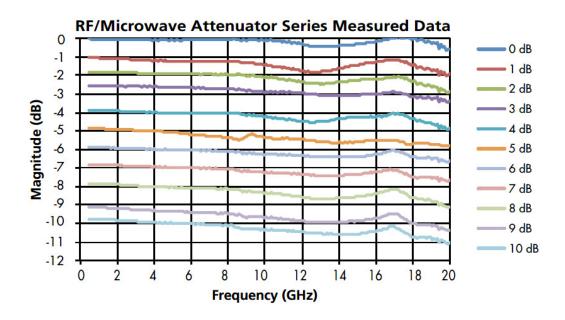
Click on part number to see full specifications



For RoHS compliant products, please select correct termination style

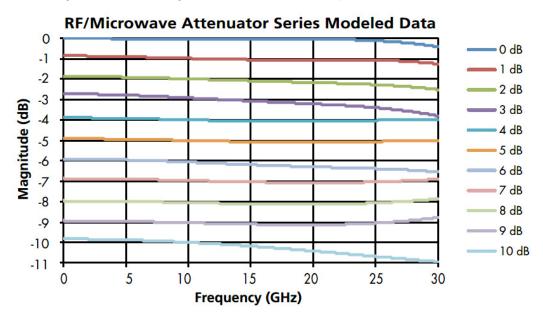
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RF/MICROWAVE ATTENUATOR TEST CONDUCTION DESCRIPTION

All testing performed on 13.3-mil-thick Rogers RO4350 microstrip board, with the UUT subtending a 44 mil gap in 30 mil-wide center trace (nominal 50-ohm characteristic impedance). Measurements were made using a four-receiver architecture. Measurements have been de-embedded to the edges of the UUT using a standard TRL calibration procedure.

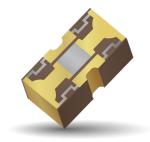


RF/MICROWAVE ATTENUATOR MODELED DATA DESCRIPTION

Models were simulated using Ansoft HFSS version 14 in a perfect 50 ohm environment with ideal ports placed at the edge of the pads to ground. The boundary condition was set to be a radiating boundary in air.

AT0603T00ECATD - 0dB



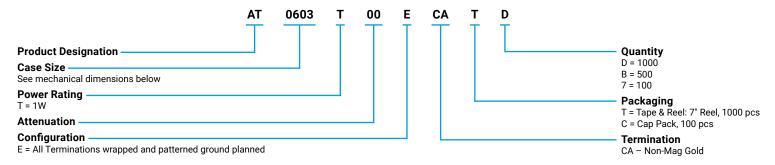


QUALIFICATION TEST SUMMARY

Input Power C	/: 1W	Tolerance (dB):	D.C. to 10 GHz:±0.50 dB >10GHz: ±dB
Frequency Rang	DC to 20 GHz	Resistors:	Tantalum Nitride
VSM	1.25:1 Typical	Terminal:	Thin Film Metalstack, Au
Nominal Impedance	50 Ohms	Substrate Material:	Al_2O_3
Operating Temperatur	-55°C to + 150°C	Inspection:	100% Per MIL-STD-883

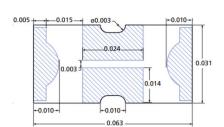
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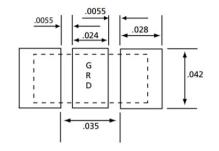
HOW TO ORDER



MECHAINCAL DIMENSIONS

Dimensions are in inches, Bottom View







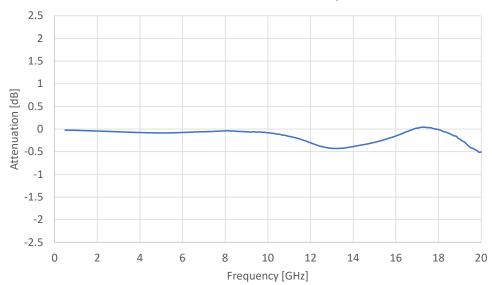


For RoHS compliant products, please select correct termination style



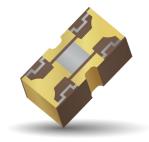
*Data files contain DXF, S2P, and HFSS files

Measured OdB Attenuator on Microstrip Board



AT0603T01ECATD - 1dB



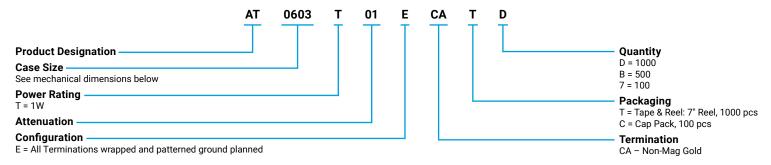


QUALIFICATION TEST SUMMARY

Input Power CW	1W	Tolerance (dB):	D.C. to 10 GHz:±0.50 dB >10GHz: ±dB
Frequency Range	DC to 20 GHz	Resistors:	Tantalum Nitride
VSMR	1.25:1 Typical	Terminal:	Thin Film Metalstack, Au
Nominal Impedance	50 Ohms	Substrate Material:	AIN
Operating Temperature	-55°C to + 150°C	Inspection:	100% Per MIL-STD-883

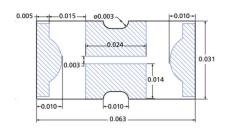
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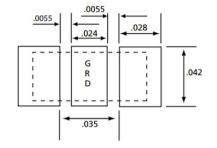
HOW TO ORDER



MECHAINCAL DIMENSIONS

Dimensions are in inches, Bottom View







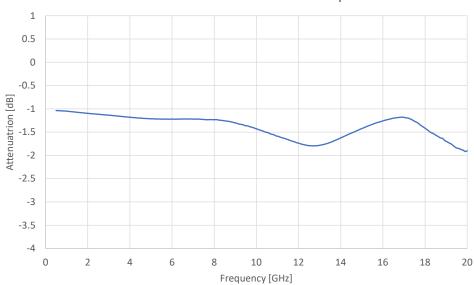


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*Data files contain DXF, S2P, and HFSS files

Measured 1dB Attenuator on Microstrip Board

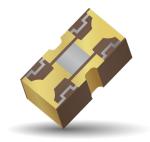


KYDCERa | The Important Information/Disclaimer is incorporated in the catalog where these specifications came from or available online at www.avx.com/disclaimer/ by reference and should be reviewed in full before placing any order.

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AT0603T02ECATD - 2dB



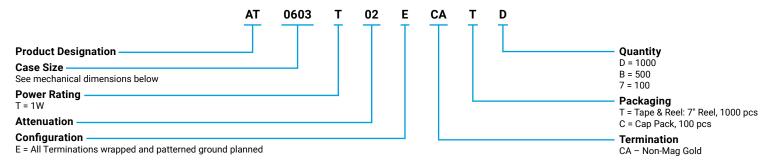


QUALIFICATION TEST SUMMARY

Input Power CW:	1W	Tolerance (dB):	D.C. to 10 GHz:±0.50 dB >10GHz: ±dB
Frequency Range:	DC to 20 GHz	Resistors:	Tantalum Nitride
VSMR	1.25:1 Typical	Terminal:	Thin Film Metalstack, Au
Nominal Impedance	50 Ohms	Substrate Material:	AIN
Operating Temperature:	-55°C to + 150°C	Inspection:	100% Per MIL-STD-883

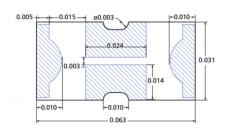
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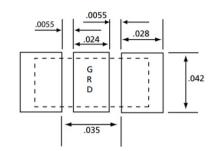
HOW TO ORDER



MECHAINCAL DIMENSIONS

Dimensions are in inches, Bottom View







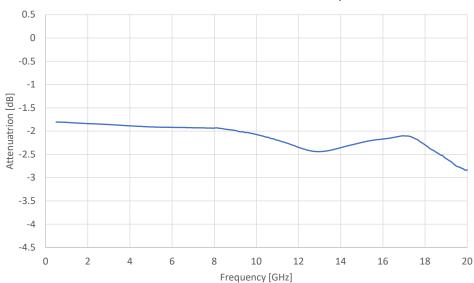


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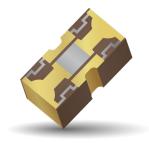
*Data files contain DXF, S2P, and HFSS files

Measured 2dB Attenuator on Microstrip Board



AT0603T03ECATD - 3dB



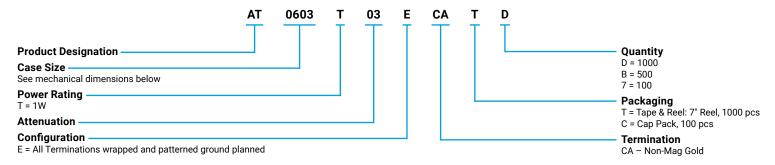


QUALIFICATION TEST SUMMARY

Input Power CW:	1W	Tolerance (dB):	D.C. to 10 GHz:±0.50 dB >10GHz: ±dB
Frequency Range:	DC to 20 GHz	Resistors:	Tantalum Nitride
VSMR:	1.25:1 Typical	Terminal:	Thin Film Metalstack, Au
Nominal Impedance:	50 Ohms	Substrate Material:	AIN
Operating Temperature:	-55°C to + 150°C	Inspection:	100% Per MIL-STD-883

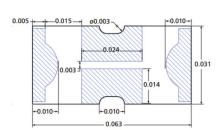
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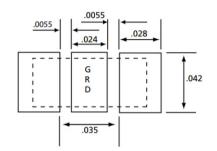
HOW TO ORDER



MECHAINCAL DIMENSIONS

Dimensions are in inches, Bottom View







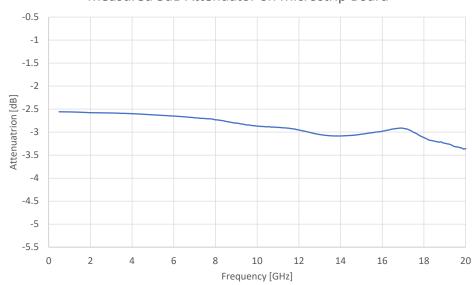


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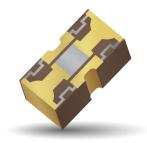
*Data files contain DXF, S2P, and HFSS files

Measured 3dB Attenuator on Microstrip Board



AT0603T04ECATD - 4dB



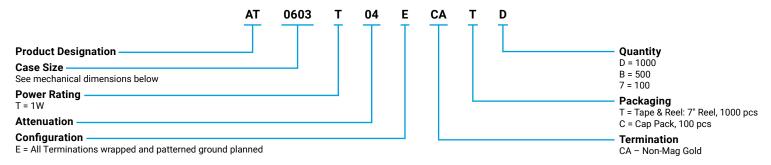


QUALIFICATION TEST SUMMARY

Input Power CW:	1W	Tolerance (dB):	D.C. to 10 GHz:±0.50 dB >10GHz: ±dB
Frequency Range:	DC to 20 GHz	Resistors:	Tantalum Nitride
VSMR	1.25:1 Typical	Terminal:	Thin Film Metalstack, Au
Nominal Impedance	50 Ohms	Substrate Material:	AIN
Operating Temperature:	-55°C to + 150°C	Inspection:	100% Per MIL-STD-883

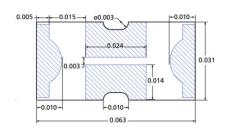
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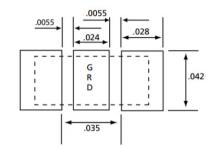
HOW TO ORDER



MECHAINCAL DIMENSIONS

Dimensions are in inches, Bottom View







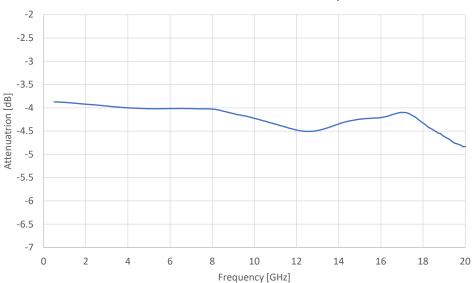


For RoHS compliant products, please select correct termination style



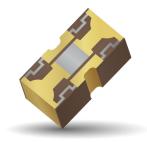
*Data files contain DXF, S2P, and HFSS files

Measured 4dB Attenuator on Microstrip Board



AT0603T05ECATD - 5dB



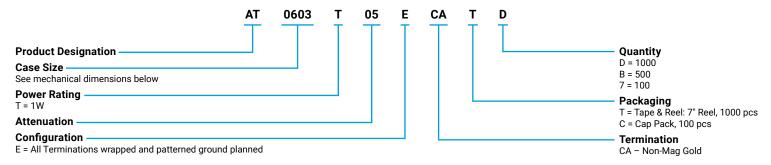


QUALIFICATION TEST SUMMARY

Input Power CW:	1W	Tolerance (dB):	D.C. to 10 GHz:±0.50 dB >10GHz: ±dB
Frequency Range:	DC to 20 GHz	Resistors:	Tantalum Nitride
VSMR:	1.25:1 Typical	Terminal:	Thin Film Metalstack, Au
Nominal Impedance:	50 Ohms	Substrate Material:	AIN
Operating Temperature:	-55°C to + 150°C	Inspection:	100% Per MIL-STD-883

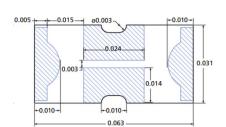
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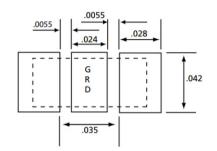
HOW TO ORDER



MECHAINCAL DIMENSIONS

Dimensions are in inches, Bottom View







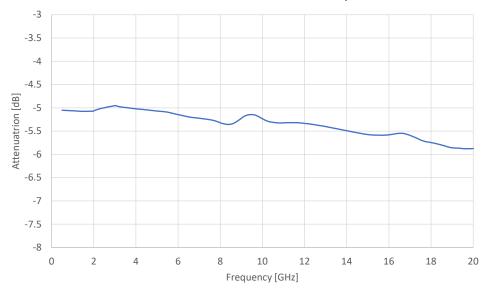


For RoHS compliant products, please select correct termination style



*Data files contain DXF, S2P, and HFSS files

Measured 5dB Attenuator on Microstrip Board



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AT0603T06ECATD - 6dB



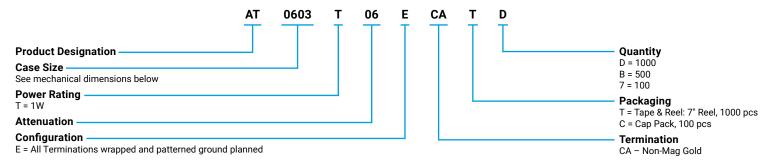


QUALIFICATION TEST SUMMARY

Input Power CW	1W	Tolerance (dB):	D.C. to 10 GHz:±0.50 dB >10GHz: ±dB
Frequency Range	DC to 20 GHz	Resistors:	Tantalum Nitride
VSMR	1.25:1 Typical	Terminal:	Thin Film Metalstack, Au
Nominal Impedance	50 Ohms	Substrate Material:	AIN
Operating Temperature	-55°C to + 150°C	Inspection:	100% Per MIL-STD-883

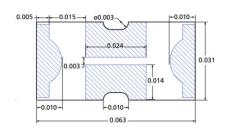
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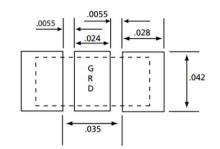
HOW TO ORDER



MECHAINCAL DIMENSIONS

Dimensions are in inches, Bottom View







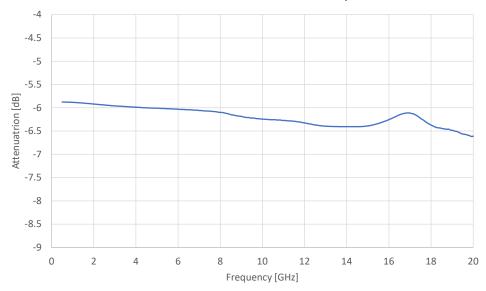


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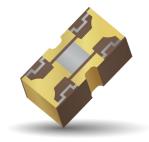
*Data files contain DXF, S2P, and HFSS files

Measured 6dB Attenuator on Microstrip Board



AT0603C07ECATD - 7dB



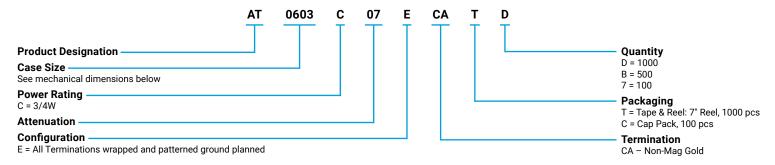


QUALIFICATION TEST SUMMARY

Input Power CW:	3/4W	Tolerance (dB):	D.C. to 10 GHz:±0.50 dB >10GHz: ±dB
Frequency Range:	DC to 20 GHz	Resistors:	Tantalum Nitride
VSMR:	1.25:1 Typical	Terminal:	Thin Film Metalstack, Au
Nominal Impedance:	50 Ohms	Substrate Material:	AIN
Operating Temperature:	-55°C to + 150°C	Inspection:	100% Per MIL-STD-883

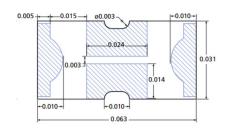
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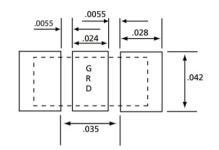
HOW TO ORDER



MECHAINCAL DIMENSIONS

Dimensions are in inches, Bottom View







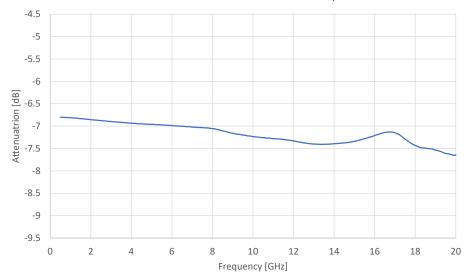


For RoHS compliant products, please select correct termination style



*Data files contain DXF, S2P, and HFSS files

Measured 7dB Attenuator on Microstrip Board



AT0603C08ECATD - 8dB



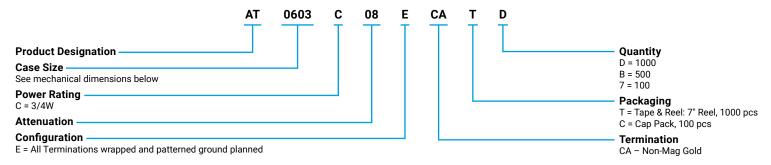


QUALIFICATION TEST SUMMARY

Input Power CW:	3/4W	Tolerance (dB):	D.C. to 10 GHz:±0.50 dB >10GHz: ±dB
Frequency Range:	DC to 20 GHz	Resistors:	Tantalum Nitride
VSMR:	1.25:1 Typical	Terminal:	Thin Film Metalstack, Au
Nominal Impedance:	50 Ohms	Substrate Material:	AIN
Operating Temperature:	-55°C to + 150°C	Inspection:	100% Per MIL-STD-883

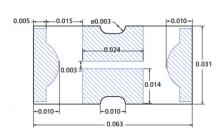
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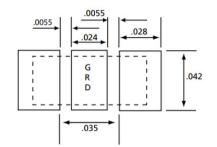
HOW TO ORDER



MECHAINCAL DIMENSIONS

Dimensions are in inches, Bottom View







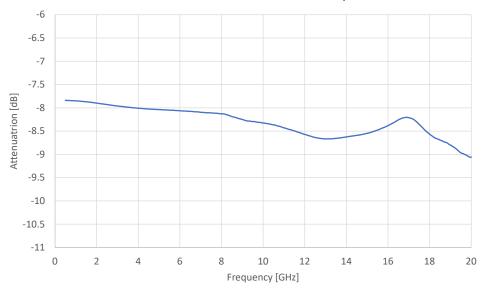


For RoHS compliant products, please select correct termination style



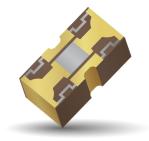
*Data files contain DXF, S2P, and HFSS files

Measured 8dB Attenuator on Microstrip Board



AT0603C09ECATD - 9dB



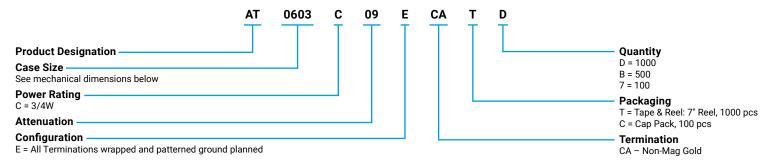


QUALIFICATION TEST SUMMARY

Input Power (N: 3/4W	Tolerance (dB):	D.C. to 10 GHz:±0.50 dB >10GHz: ±dB
Frequency Ran	e: DC to 20 GHz	Resistors:	Tantalum Nitride
VSI	R: 1.25:1 Typical	Terminal:	Thin Film Metalstack, Au
Nominal Impedan	e: 50 Ohms	Substrate Material:	AIN
Operating Temperato	e: -55°C to + 150°C	Inspection:	100% Per MIL-STD-883

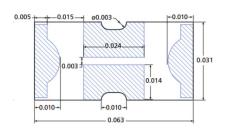
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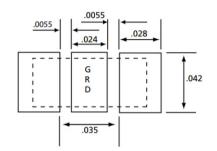
HOW TO ORDER



MECHAINCAL DIMENSIONS

Dimensions are in inches, Bottom View







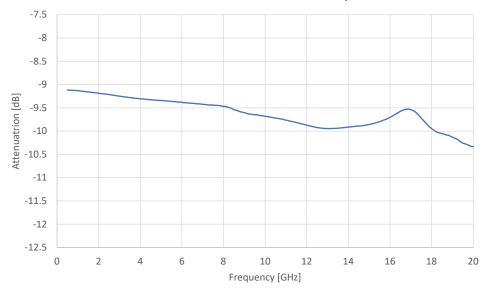


For RoHS compliant products, please select correct termination style



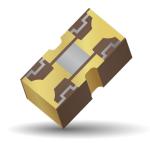
*Data files contain DXF, S2P, and HFSS files

Measured 9dB Attenuator on Microstrip Board



AT0603C10ECATD - 10dB



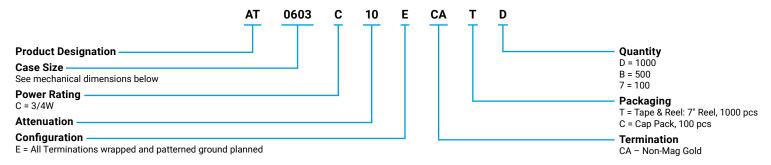


QUALIFICATION TEST SUMMARY

Input Power CW	3/4W	Tolerance (dB):	D.C. to 10 GHz:±0.50 dB >10GHz: ±dB
Frequency Range	DC to 20 GHz	Resistors:	Tantalum Nitride
VSMR	1.25:1 Typical	Terminal:	Thin Film Metalstack, Au
Nominal Impedance	50 Ohms	Substrate Material:	AIN
Operating Temperature	-55°C to + 150°C	Inspection:	100% Per MIL-STD-883

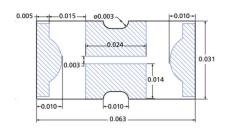
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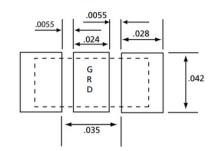
HOW TO ORDER



MECHAINCAL DIMENSIONS

Dimensions are in inches, Bottom View









For RoHS compliant products, please select correct termination style



*Data files contain DXF, S2P, and HFSS files

Measured 10dB Attenuator on Microstrip Board

